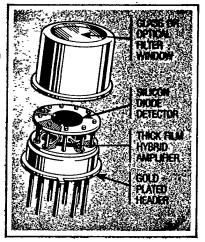
PHOTO DETECTOR WITH AMPLIFIER

CUSTOM OPTICAL FILTERS AVAILABLE

DEVAR, Inc. TYPE

529

SERIES



INCLUDING NARROW BANDPASS AND PHOTOPIC

The Devar type 529 optical detectors are unique transducers, converting incident radiometric optical power into electronic power, current or voltage. Power gains of 108 are readily achieved. Standard units offer useful optical bandwidths from wave lengths (λ) of 400 nanometers (near UV) through the visible to 1100 nanometers in the near infra red. Extended response, either side is available with special detectors.

This series of detectors is designed for very high optical sensitivity (down to 10⁻¹¹ watts), and medium frequency electronic bandwidth. 529's are really an electro-optical transducer and preamplifier combined in a miniature T0-5, hermetically sealed, integrated circuit package, built to military standard practices.

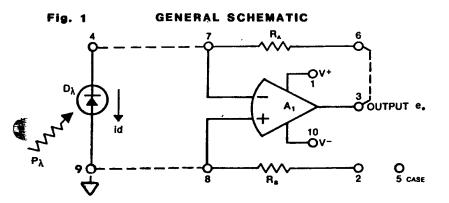


Fig. 1 shows the schemauc with pin numbers. The essential elements are: detector, amplifier, and gain resistors. (Dotted lines show typical hook-up.)

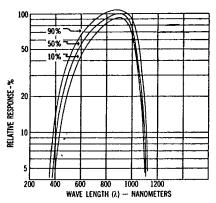
1. Silicon Photodiode (Da). It is an extremely linear current source (over 10 decades), in response to incident optical power, Pλ.

Two different size diodes are available, with characteristics shown in Table I.

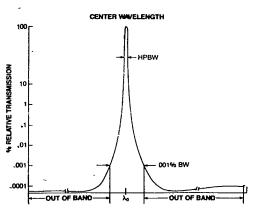
- 2. A high gain, high input impedance operational amplifier, A1 of predictable behavior, generally operated from dual supplies. Characteristics are shown in Table II.
- 3. Two equal value resistors, (RA, RB) useful in setting gain (and in other ways), are connected to the (+) and (-) input terminals of A₁. They are available in two standard values (2x106, and 1x1051). Nominal tolerance is 20%. Differential tolerance is 10%.

The first objective of the 529 is to combine these four high impedance elements in close proximity within a shielded (metal) package, to reduce external noise pickup. Otherwise, external noise would determine the achievable "signal to noise" ratio, not the components themselves.

The second objective is to provide a very flexible pinout arrangement, whereby, the elements may be externally connected to achieve a variety of circuit forms, allowing gain, bandwidth, and dark offset to be easily controlled by the user.



SPECTRAL RESPONSIVITY DISTRIBUTION.



TYPICAL FILTER OPTION CENTER WAVELENGTH ACCURACY # 1.5 NM

ORDER OPTIONS:

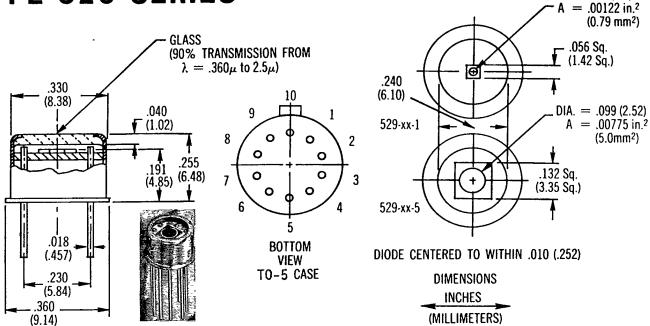
Part Number	RA, RB	Diode Area
529-2-1	2x10 ⁶ Ohms	0.8mm ²
529-2-5	2x106 Ohms	5.0mm ²
529-01-1	100K Ohms	0.8mm ²
529-01-5	100K Ohms	5.0mm ²

PHOTO DETECTOR WITH AMPLIFIER

T-41-67

DIA. = .039(1.0)

TYPE 529 SERIES



Photodiode Characteristics: $(V_d = OV, T_A = 25^{\circ}C, unless noted)$

PARAMETER	SYMBOL.	-1	-5	UNITS	CONDITIONS
Diode Responsivity	Κλ	0.6	0.6	Amperes Watts	λ = 0.9 x 10 ⁻⁶ Meters
Luminous Responsivity	Kλ _(L)	8.5	8.5	mA/lm	T _s = 2854° K
Resistance	₽ď	140 x 10 ⁵	50 x 10 ⁶	Ohms	
Capacitance	Сd	15 x 10 ⁻¹²	45 x 10 ⁻¹²	Farads	
Dark Current	ld	2 x 10 ⁻⁹	5 x 10 ⁻⁹	Amperes	$V_d = -15 \text{ Volts}$
Active Area	A _d	0.8	5.0	mṁ²	
Active Dia.	φ _d	1.0	2.52	mm	
Reverse Bias Voltage	− V _d	0-45	0-45	Volts	Limits
Max. Allowable Irradiance	I _{max}	.03	.03 -	Watts mm ²	Steady State

Amplifier Characteristics: $(V_s = \pm 15V, T_A = 25^{\circ}C, \text{ unless noted})$

PARAMETER	SYMBOL	VALUE - 80 PERCENTILE UNITS		CONDITIONS
Input Bias Current	l _B	2 x 10 ⁻⁹	Amperes	
vs. Temp.	dl _B /dT	−1 x 10 ⁻¹¹	A/°C	
Input Offset Voltage	Eos	±5 x 10 ⁻³	Volts	
vs. Temp.	dE _{os} /dT	±10 x 10 ⁻⁶	V/°C	
Open Loop Unity Gain Cross Over Frequency	fx	2 x 10 ⁶ Hz		Small Signal
Slew Rate Limit	de _o /dT	5 x 10 ⁵ V/Sec.		e _o = 20V P-P
Output: Current	lo	±5 x 10 ⁻³	Amperes	$R_L = 2 \times 10^3 \Omega$
Voltage	V _o	±10	Volts	$R_L = 2 \times 10^3 \Omega$
Supply: Current	:Lls	1 x 10 ⁻³	Amperes	$V_s = \pm 3$ to 18V
Voltage	±V _s Min. → V _s Max.	3 18	Volts Volts	
Input Resistance	R,	40 x 10 ⁶	Ohms	

TABLE 2

TABLE 1

ADDITIONAL APPLICATION NOTES AVAILABLE

DEVAR, Inc. IDGEPORT, CT 06605

FOR MORE INFORMATION CONTACT:

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